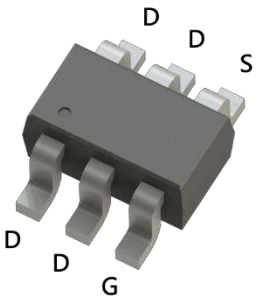
P-Channel Enhancement Mode MOSFET

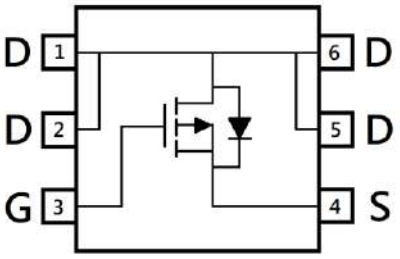
Features:

- Low On Resistance
- Low Gate Charge
- Fast Switching Characteristic

SOT-26



BV_{DSS}	-150V
I_D@ V_{GS}=-10V, T_A=25°C	-0.95A
$R_{DS(ON)}$ typ.@ V_{GS}=-10V, I_D=-1A	555mΩ



G : Gate S : Source D : Drain

Ordering Information

Device	Package	Shipping
KTTF1P15A	SOT-26 (Pb-free lead plating and halogen-free package)	3000 pcs / Tape & Reel

Absolute Maximum Ratings (T_A=25°C)

Parameter		Symbol	Limits	Unit
Drain-Source Voltage		V_{DS}	-150	V
Gate-Source Voltage		V_{GS}	±20	
Continuous Drain Current @ V_{GS}=-10V, T_A=25°C	*a	I_D	-0.95	A
Continuous Drain Current @ V_{GS}=-10V, T_A=70°C	*a		-0.76	
Pulsed Drain Current	*b	I_{DM}	-3.8	
Continuous Body Diode Forward Current @ T_A=25°C	*a	I_S	-0.95	
Total Power Dissipation	T_A=25°C *a	P_D	1.5	W
	T_A=70°C *a		1	
Operating Junction and Storage Temperature Range		T_J, T_{stg}	-55~+150	°C

Thermal Data

Parameter		Symbol	Steady State	Unit
Thermal Resistance, Junction-to-ambient	*a	$R_{\theta JA}$	85	°C/W

Note:

*a. The value of $R_{\theta JA}$ is measured with the device mounted on 1 in^2 FR -4 board with 2 oz. copper, in a still air environment with T_A=25℃. The power dissipation P_D is based on $R_{\theta JA}$ and the maximum allowed junction temperature of 150℃. The value in any given application depends on the user's specific board design.

*b. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}$=150℃. Ratings are based on low frequency and low duty cycles to keep initial T_J=25℃.

Electrical Characteristics (T_A=25°C, unless otherwise specified)

Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Static					
BV_{DSS}	-150	-	-	V	V_{GS}=0V, I_D=-250μA
$V_{GS(th)}$	-2	-	-4		V_{DS}=V_{GS}, I_D=-250μA
G_{FS}	-	2.4	-	S	V_{DS}=-10V, I_D=-1A
I_{GSS}	-	-	±100	nA	V_{GS}=±20V, V_{DS}=0V
I_{DSS}	-	-	-1	μA	V_{DS}=-120V, V_{GS}=0V
$R_{DS(ON)}$	-	555	820	mΩ	V_{GS}=-10V, I_D=-1A
Dynamic					
Ciss	-	480	-	pF	V_{DS}=-75V, V_{GS}=0V, f=1MHz
Coss	-	28	-		
Crss	-	22	-		
Qg *1, 2	-	11	-	nC	V_{DS}=-75V, I_D=-1A, V_{GS}=-10V
Qgs *1, 2	-	2.6	-		
Qgd *1, 2	-	2.6	-		
$t_{d(ON)}$ *1, 2	-	9.8	-	ns	V_{DS}=-75V, I_D=-1A, V_{GS}=-10V, R_{GS}=6Ω
tr *1, 2	-	17	-		
$t_{d(OFF)}$ *1, 2	-	32	-		
t_f *1, 2	-	28	-		
Source-Drain Diode					
V_{SD} *1	-	-0.77	-1.2	V	I_S=-1A, V_{GS}=0V
trr	-	28	-	ns	I_F=-1A, dI_F/dt=100A/μs
Qrr	-	33	-	nC	

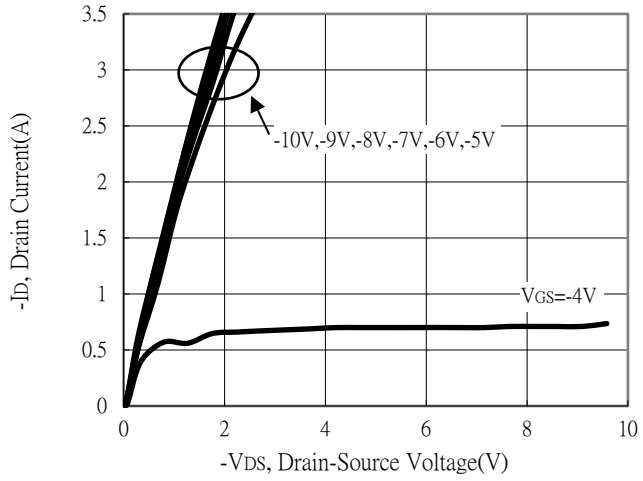
Note:

*1. Pulse Test : Pulse Width ≤300μs, Duty Cycle≤2%

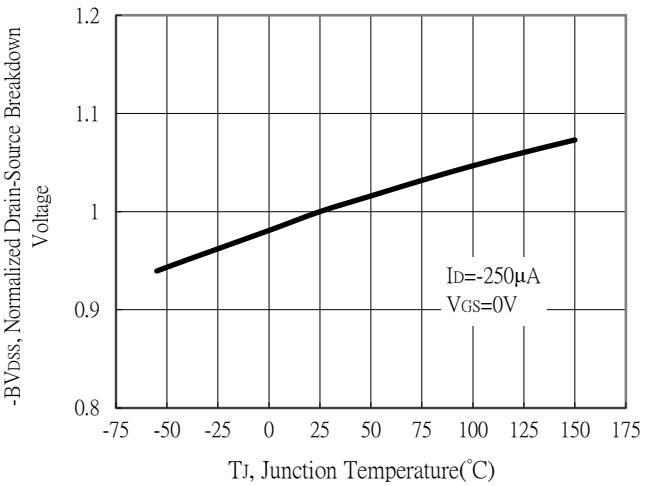
*2. Independent of operating temperature

Typical Characteristics

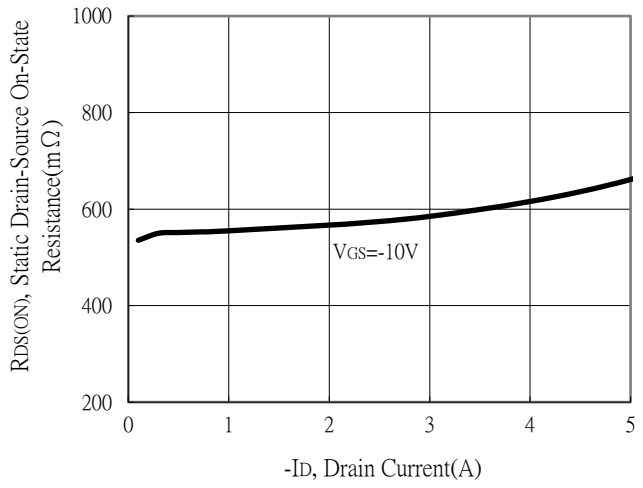
Typical Output Characteristics



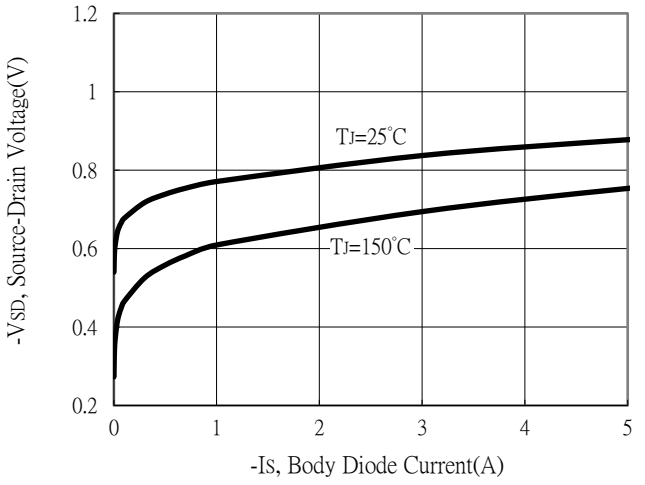
Breakdown Voltage vs Ambient Temperature



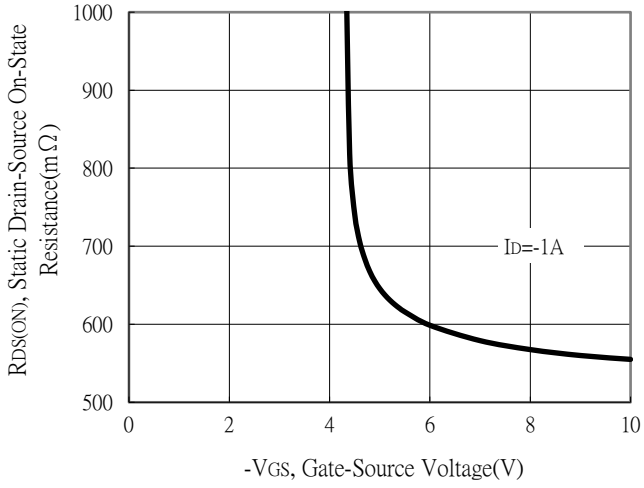
Static Drain-Source On-State resistance vs Drain Current



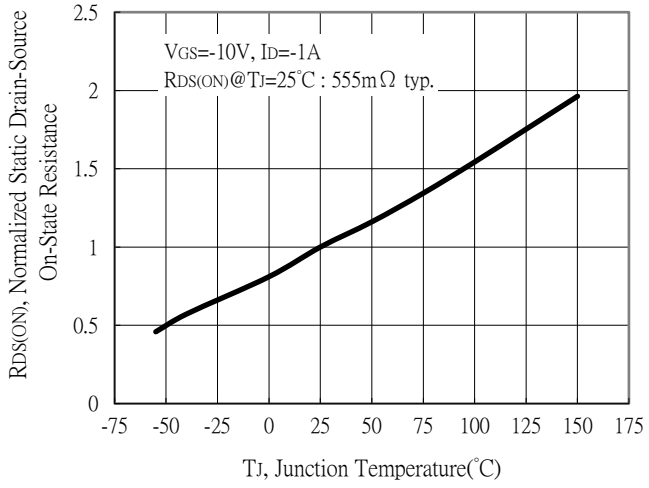
Body Diode Current vs Source-Drain Voltage



Static Drain-Source On-State Resistance vs Gate-Source Voltage

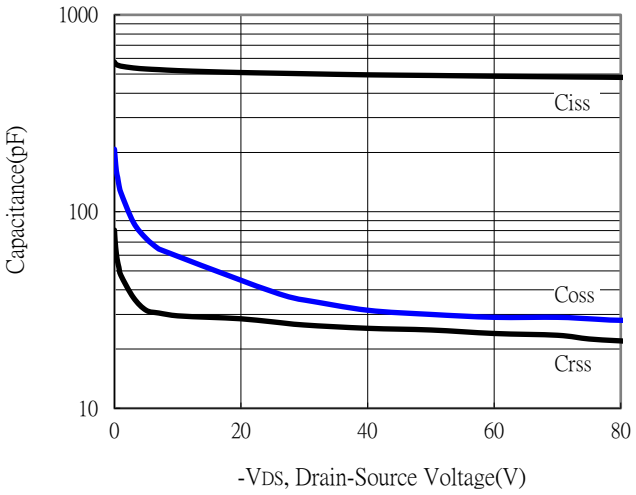


Drain-Source On-State Resistance vs Junction Temperature

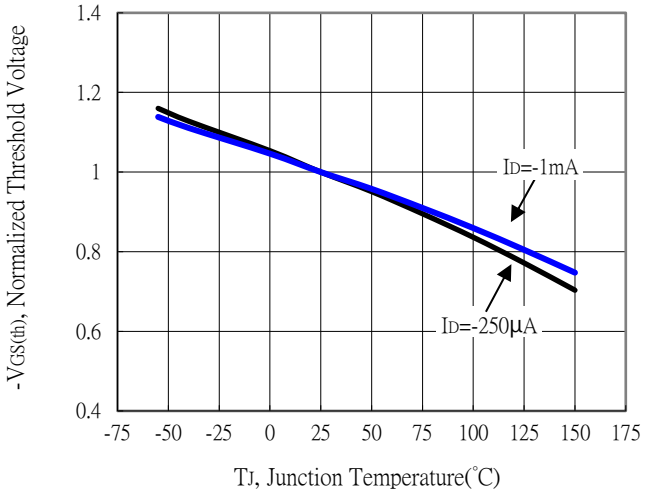


Typical Characteristics (Cont.)

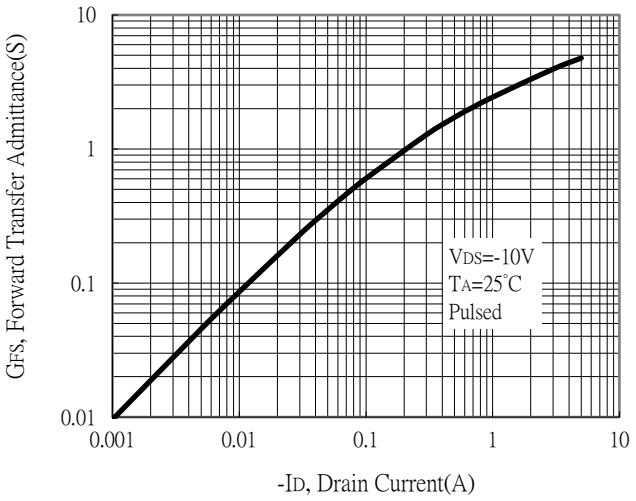
Capacitance vs Drain-to-Source Voltage



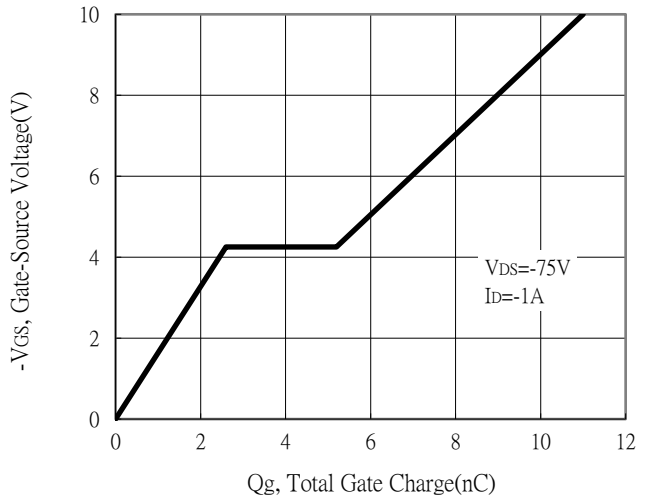
Threshold Voltage vs Junction Temperature



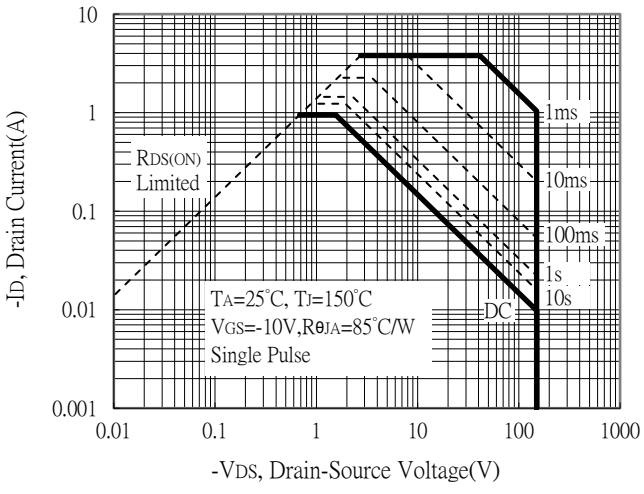
Forward Transfer Admittance vs Drain Current



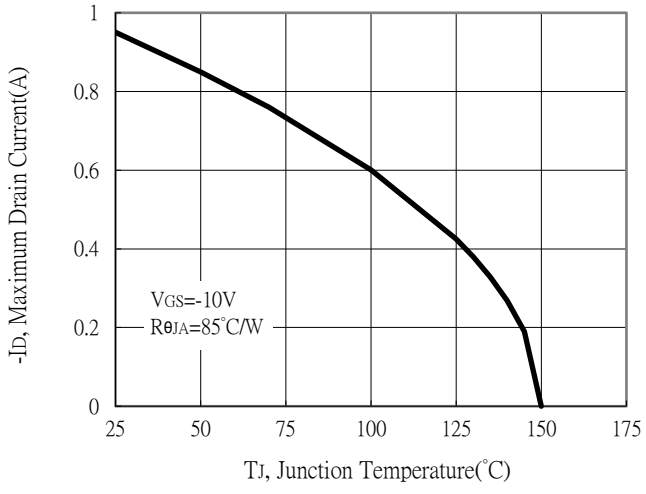
Gate Charge Characteristics



Maximum Safe Operating Area

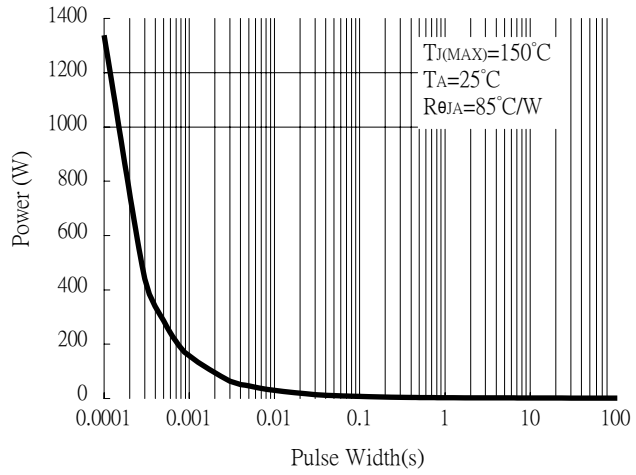


Maximum Drain Current vs Junction Temperature

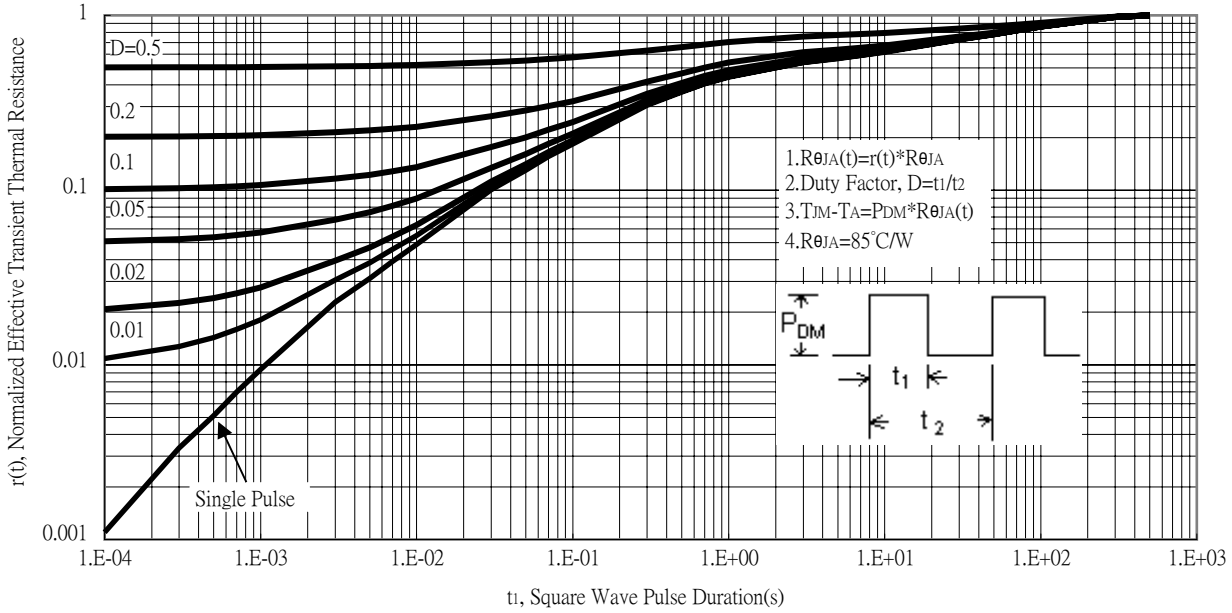


Typical Characteristics (Cont.)

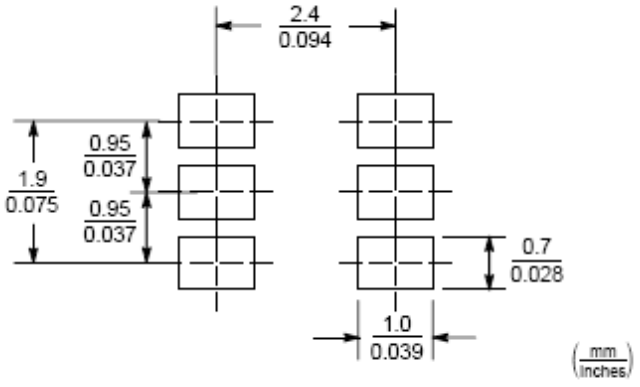
Single Pulse Power Rating, Junction to Ambient



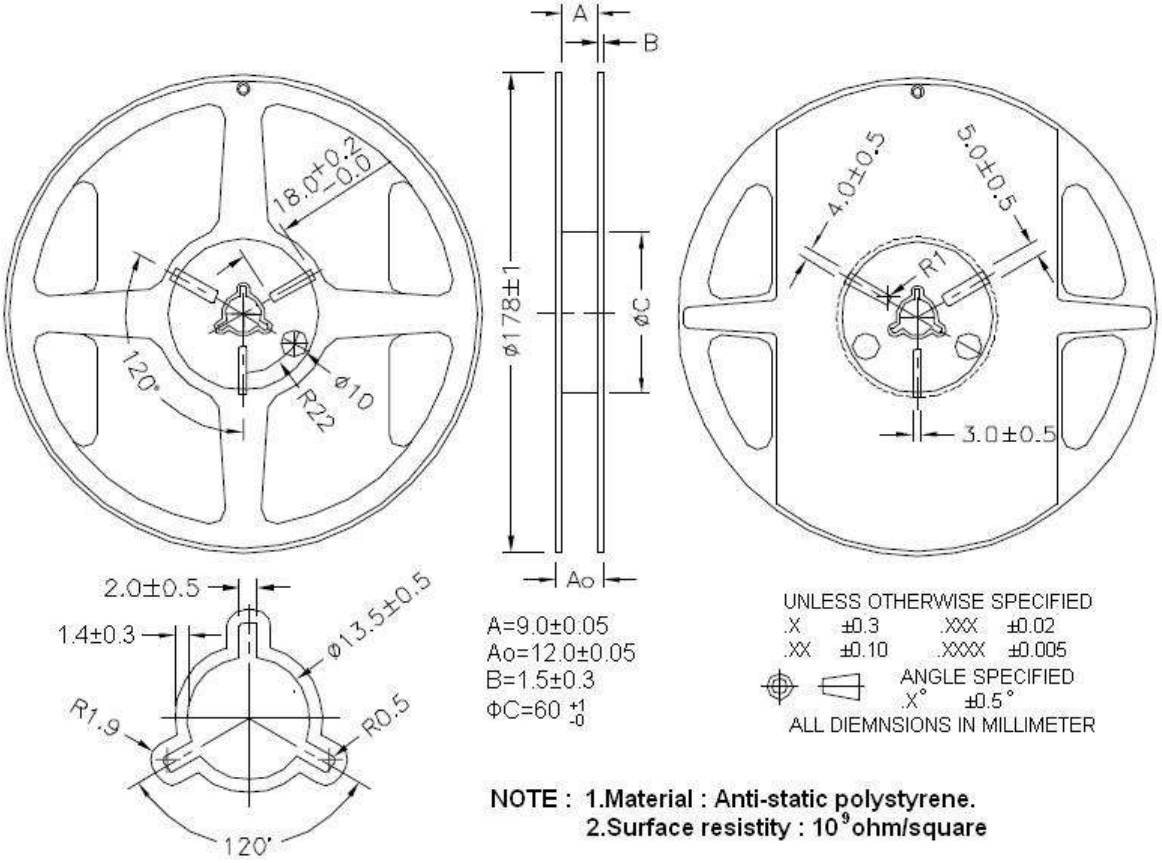
Transient Thermal Response Curves



Recommended Soldering Footprint

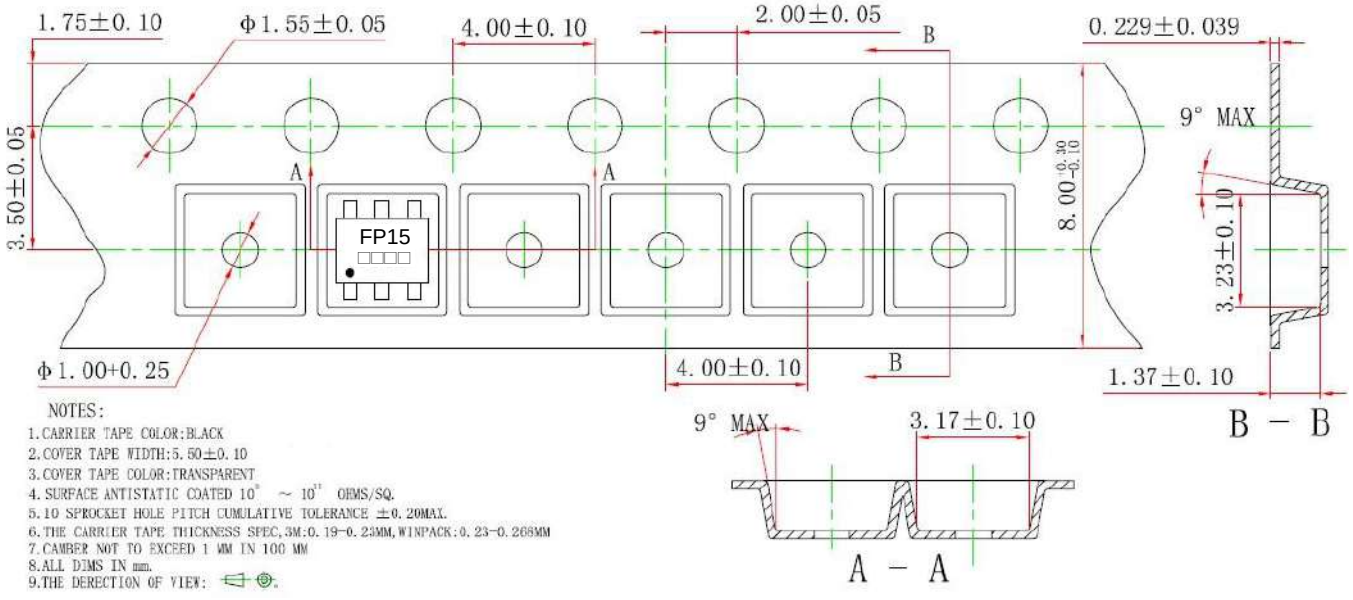


Reel Dimension



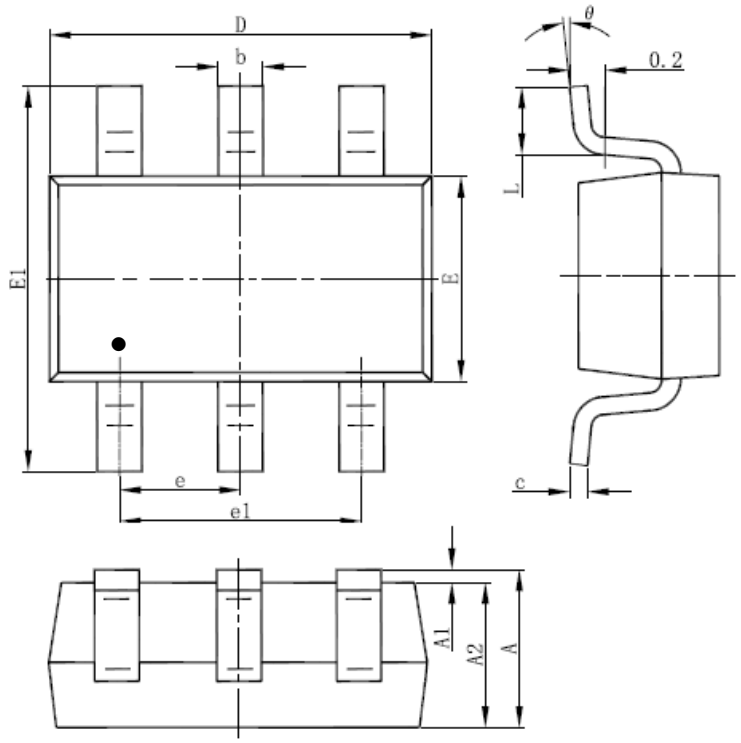
NOTE : 1.Material : Anti-static polystyrene.
2.Surface resistity : 10^9 ohm/square

Carrier Tape Dimension



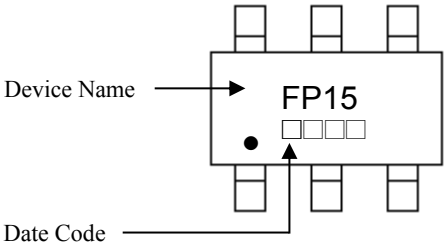
NOTES:
1. CARRIER TAPE COLOR: BLACK
2. COVER TAPE WIDTH: 5.50±0.10
3. COVER TAPE COLOR: TRANSPARENT
4. SURFACE ANTISTATIC COATED 10^8 ~ 10^{11} OHMS/SQ.
5. 10 SPROCKET HOLE PITCH CUMULATIVE TOLERANCE ±0.20MAX.
6. THE CARRIER TAPE THICKNESS SPEC, 3M: 0.19~0.23MM, WINPACK: 0.23~0.268MM
7. CAMBER NOT TO EXCEED 1 MM IN 100 MM
8. ALL DIMS IN mm.
9. THE DERECTION OF VIEW:

SOT-26 Dimension



6-Lead SOT-26 Plastic
Surface Mounted Package

Marking:



Style:
Pin 1. Drain (D)
Pin 2. Drain (D)
Pin 3. Gate (G)
Pin 4. Source (S)
Pin 5. Drain (D)
Pin 6. Drain (D)

Date Code(counting from left to right) :
1st code: year code, the last digit of Christian year
2nd code : month code, Jan→A, Feb→B, Mar→C,
Apr→D, May→E, Jun→F, Jul→G, Aug→H,
Sep→J, Oct→K, Nov→L, Dec→M
3rd and 4th codes : production serial number, 01~99

DIM	Millimeters		Inches		DIM	Millimeters		Inches	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	1.050	1.250	0.041	0.049	E	1.500	1.700	0.059	0.067
A1	0.000	0.100	0.000	0.004	E1	2.650	2.950	0.104	0.116
A2	1.050	1.150	0.041	0.045	e	0.950 (BSC)		0.037 (BSC)	
b	0.300	0.500	0.012	0.020	e1	1.800	2.000	0.071	0.079
c	0.100	0.200	0.004	0.008	L	0.300	0.600	0.012	0.024
D	2.820	3.020	0.111	0.119	θ	0°	8°	0°	8°